

CS1030 Solid State Drive



High Performance Transfer speed faster than a traditional SATA based storage



Enhanced Reliability Non-volatile NAND up to 30 times more robust than HDDs



Extended protection and peace of mind

CS1030 SOLID STATE DRIVES

The PNY CS1030 M.2 NVMe SSD is an excellent choice for an NVMe upgrade from a SATA based solid state drive (SSD) or traditional hard drive in an NVMe enabled desktop or laptop computer. The CS1030 drive is designed to be an upgrade from conventional SATA based storage to take advantage of the high bandwidth of the NVMe interface to help realize faster boot times, quicker application launches, and better overall system performance. Do more in less time with NVMe; boot up, power down, and load applications up to 4 times faster than with SATA based SSD's.

The NVMe interface delivers exceptional performance of up to 2,500 MB/s seq. read and 1,900 MB/s seq. write speeds. It is designed to be a high performance replacement for traditional SATA based storage to help realize faster boot times, quicker application launches, and better overall system performance. With no moving parts, the PNY CS1030 M.2 NVMe SSD is highly durable, less likely to fail, and supports a 5-year limited warranty or TBW.*

The PNY CS1030 is engineered with the same level of quality and durability that our consumers have enjoyed with the CS900 SSD. We've taken the world's most advanced NAND flash and refined the CS1030 to achieve a higher threshold for endurance and reliability. PNY's extensive testing and rigorous validation process ensures compatibility across various platforms and multiple operating systems.

APPLICATIONS

- NVMe upgrade from a SATA based solid state drive (SSD) or a traditional hard disk drive in an NVMe enabled desktop or laptop computer
- High performance SSD with up to 4 times the performance as compared to SATA based SSDs

FEATURES AND BENEFITS

- Sequential Read of up to 2,500 MB/s and Write of up to 1,900 MB/s
- · Faster boot up and quicker application launch
- Better overall system performance
- Reliable storage
- · Low power consumption, cool and quiet operation

PRODUCT SPECIFICATIONS NAND Components 3D Flash Memory Interface PCIe Gen3 x4 Form Factor M.2 2280 PERFORMANCE (MAX SEQUENTIAL READ/WRITE) 2,500 MB/s (Read), 1,100 MB/s (Write) 250GB 500GB 2,000 MB/s (Read), 1,100 MB/s (Write) 2,100 MB/s (Read), 1,700 MB/s (Write) 1TB 2TB 2,100 MB/s (Read), 1,900 MB/s (Write) POWER PCIe Power Management APST, ASPM, L1.2 ENVIRONMENTAL 0°C ~ 70°C **Operating Temperature** -40°C ~ 85°C Storage Temperature BSMI, CE, FCC, KCC, REACH, RoHS, VCCI Certifications RELIABILITY/SECURITY Mean Time Between Failures (MTBF) 2.000.000 Hours LDPC (Low Density Parity Check) ECC Algorithm Error Correction Code Self-Monitoring, Analysis and Reporting Technology (S.M.A.R.T) Product Health Monitoring Full End-to-End Data path protection Supported COMPATIBILITY RAID (0/1) Supported NVMe NVMe 1.3 **ADDITIONAL FEATURES** Performance Optimization TRIM (requires OS support) **PRODUCT INFORMATION** Service & Support 5-Year Limited Warranty or TBW* Usable Capacities (IDEMA) 250GB, 500GB, 1TB, 2TB 250GB: M280CS1030-250-RB 500GB: M280CS1030-500-RB 1TB: M280CS1030-1TB-RB PNY Part Number

2TB: M280CS1030-2TB-RB

250GB: 751492642444 500GB: 751492641621 1TB: 751492641638 2TB: 751492641645

3.9" x 2.75" x 0.25'

6.6q

22 x 80 x 4 mm (Max)

*For full details visit www.pnv.com

UPC

Weight

Box Dimensions

Dimensions (L x W x H)

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